

CLMPTO

RS

CLAIMS 1 – 12 (CANCELLED)

13. (New) A method for manufacturing a display apparatus including a thin film transistor formed over a substrate, the thin film transistor having a source electrode and a drain electrode, and an electroluminescence element formed over the thin film transistor and having a luminous element layer between a lower electrode and an upper electrode, wherein

the lower electrode, the luminous element layer, and the upper electrode of the electroluminescence element are formed over the thin film transistor in that order, the upper electrode being formed using a non-transparent metal material and through evaporation so that the upper electrode has a planar shape covering a portion of a display pixel region in a unit display pixel region, and

light emission from the electroluminescence element is emitted to the outside from an upper electrode side opposite of the substrate.

14. (New) A method for manufacturing a display apparatus according to Claim 13, wherein

one of the source electrode and the drain electrode of the thin film transistor is electrically connected to the lower electrode of the electroluminescence element.

Art Unit: ***

15. (New) A method for manufacturing a display apparatus according to Claim 13, wherein

light emission from the electroluminescence element is emitted through an opening region which is not covered by the upper electrode within the unit display pixel region on the side near the upper electrode positioned opposite of the substrate.

16. (New) A method for manufacturing a display apparatus comprising the steps of:

forming a thin film transistor having a source electrode and a drain electrode over a substrate;

forming at least one layer of insulating film covering the thin film transistor; and

after the formation of the insulating film, forming an electroluminescence element having a luminous element layer between a lower electrode and an upper electrode, by forming a light reflective conductive material layer as a lower electrode, forming a luminous element layer, and forming an upper electrode on the luminous element layer through evaporation of a non-transparent metal material layer having a planar shape covering a portion of a display pixel region within a unit display pixel region, wherein

light emission from the electroluminescence element is emitted to the outside from the side near the upper electrode opposite of the substrate.

17. (New) A method for manufacturing a display apparatus according to Claim 16, further comprising the steps of:

forming a contact hole through the at least one layer of insulating film covering

Art Unit: ***

the thin film transistor; and

electrically connecting one of the source electrode and the drain electrode of the thin film transistor and the lower electrode of the electroluminescence element.

18. (New) A method for manufacturing a display apparatus according to Claim 16, wherein

light emission from the electroluminescence element is emitted through an opening region which is not covered by the upper electrode within the unit display pixel region on the side near the upper electrode positioned opposite of the substrate.